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SBOS074D-SEPTEMBER 1997-REVISED JANUARY 2015

ISO124 Precision Lowest-Cost Isolation Amplifier

Technical

Documents

1 Features

- 100% Tested for High-Voltage Breakdown
- Rated 1500 Vrms
- High IMR: 140 dB at 60 Hz
- 0.010% Maximum Nonlinearity
- Bipolar Operation: $V_0 = \pm 10 V$
- DIP-16 and SO-28
- Ease of Use: Fixed Unity Gain Configuration
- ±4.5-V to ±18-V Supply Range

Applications 2

- Industrial Process Control:
 - Transducer Isolator, Isolator for Thermocouples, RTDs, Pressure Bridges, and Flow Meters, 4-mA to 20-mA Loop Isolation
- Ground Loop Elimination
- Motor and SCR Control
- Power Monitoring
- PC-Based Data Acquisition
- **Test Equipment**

3 Description

Tools &

Software

The ISO124 is a precision isolation amplifier incorporating a novel duty cycle modulationdemodulation technique. The signal is transmitted digitally across a 2-pF differential capacitive barrier. With digital modulation, the barrier characteristics do not affect signal integrity, thus resulting in excellent reliability and good high-frequency transient immunity across the barrier. Both barrier capacitors are imbedded in the plastic body of the package.

Support &

Community

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The ISO124 is easy to use. No external components are required for operation. The key specifications are 0.010% maximum nonlinearity, 50-kHz signal bandwidth, and 200-µV/°C V_{OS} drift. A power supply range of ±4.5 V to ±18 V and quiescent currents of ±5 mA on V_{S1} and ±5.5 mA on V_{S2} make the ISO124 ideal for a wide range of applications.

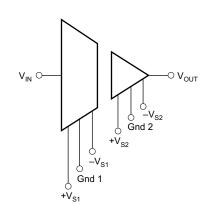
The ISO124 is available in PDIP-16 and SOIC-28 plastic surface-mount packages.

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)
180124	PDIP (16)	17.90 mm × 7.50 mm
ISO124	SOIC (28)	20.01 mm × 6.61 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Simplified Schematic





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5 **Revision History**

Changes from Revision C (September 2005) to Revision D

Added ESD Ratings table, Feature Description section, Device Functional Modes, Application and Implementation section, Power Supply Recommendations section, Layout section, Device and Documentation Support section, and Mechanical, Packaging, and Orderable Information section. 1

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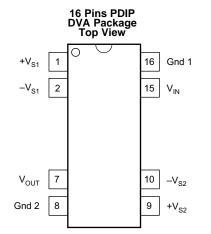
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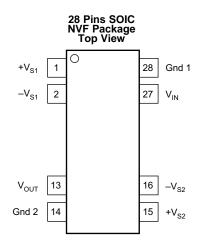
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6 Pin Configuration and Functions





Pin Functions

	PIN		I/O	DESCRIPTION				
NAME	PDIP	SOIC	1/0	DESCRIPTION				
GND	8	14	-	Low-side ground reference				
GND	16	28	-	High-side ground reference				
V _{IN}	15	27	I	ligh-side analog input				
V _{OUT}	7	13	0	Low-side analog output				
+V _{S1}	1	1	-	High-side positive analog supply				
-V _{S1}	2	2	-	High-side negative analog supply				
+V _{S2}	9	15	-	Low-side positive analog supply				
-V _{S2}	10	16	-	Low-side negative analog supply				

7 Specifications

7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) (1)

	MIN	MAX	UNIT
Supply voltage		±18	V
V _{IN}		100	V
Continuous isolation voltage		1500	Vrms
Junction temperature		125	°C
Output short to common		Continuous	
Storage temperature, T _{stg}	-40	125	°C

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

7.2 ESD Ratings

			VALUE	UNIT
	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾			
V _(ESD)	Electrostatic discharge	Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾	±500	V

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

7.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

	MIN	NOM	MAX	UNIT
T _A	-25		85	°C
V _{S1}		±15		V
V _{S2}		±15		V
V _{IN}		±10		V

7.4 Thermal Information

		ISC	ISO124			
	THERMAL METRIC ⁽¹⁾	DVA (PDIP)	NVF (SOIC)	UNIT		
		16 PINS	28 PINS			
$R_{\theta JA}$	Junction-to-ambient thermal resistance	79.8	51.0			
R _{0JC(top)}	Junction-to-case (top) thermal resistance	32.9	32.4			
$R_{ extsf{ heta}JB}$	Junction-to-board thermal resistance	42.2	29.5	°C/W		
Ψ _{JT}	Junction-to-top characterization parameter	6.6	10.4			
Ψ_{JB}	Junction-to-board characterization parameter	40.9	29.0			

(1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.



7.5 Electrical Characteristics

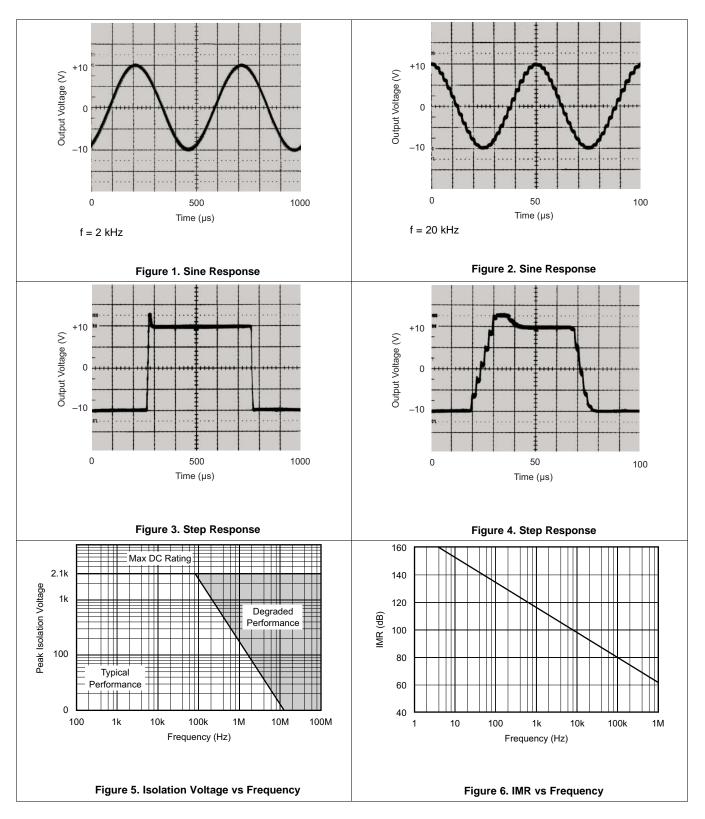
At T_{A} = +25°C , V_{S1} = V_{S2} = ±15 V, and R_{L} = 2 kΩ, unless otherwise noted.

PARAMETER		TEST CONDITIONS		UNIT			
		TEST CONDITIONS	MIN	TYP	MAX	UNIT	
SOLATION							
Rated Voltage, continuou	s ac 60 Hz		1500			Vac	
100% Test ⁽¹⁾	1:	s, 5pc PD	2400			Vac	
Isolation Mode Rejection	6	0 Hz		140		dB	
Barrier Impedance				10 ¹⁴ 2		Ω pF	
Leakage Current at 60 Hz	z V	ISO = 240 Vrms		0.18	0.5	µArms	
GAIN							
Nominal Gain	V	_O = ±10 V		1		V/V	
Gain Error	V	$O = \pm 10$ V		±0.05	±0.50	%FSR	
Gain vs Temperature				±10		ppm/°C	
Nonlinearity ⁽²⁾				±0.005	±0.010	%FSR	
NPUT OFFSET VOLTAGE							
Initial Offset				±20	±50	mV	
vs Temperature				±200		μV/°C	
vs Supply				±2		mV/V	
Noise				4		µV/√Hz	
NPUT	H						
Voltage Range			±10	±12.5		V	
Resistance				200		kΩ	
OUTPUT	H						
Voltage Range			±10	±12.5		V	
Current Drive			±5	±15		mA	
Capacitive Load Drive				0.1		μF	
Ripple Voltage ⁽³⁾				20		mVp-p	
REQUENCY RESPONSE							
Small-Signal Bandwidth				50		kHz	
Slew Rate				2		V/µs	
Settling Time 0.10%				50		μs	
Settling Time 0.01%	V	_O = ±10 V		350		μs	
Overload Recovery Time				150		μs	
POWER SUPPLIES							
Rated Voltage				±15		V	
Voltage Range			±4.5		±18	V	
Vot				±5.0	±7.0		
Quiescent Current				±5.5	±7.0	mA	
TEMPERATURE RANGE			I				
Specification			-25		85	°C	
Operating			-25		85	°C	
Storage			-40		125	°C	
				100	120	°C/W	
$\frac{R_{\theta JA}}{R_{\theta JC}}$ Thermal Resistance				65		°C/W	

Tested at 1.6 X rated, fail on 5 pC partial discharge.
Nonlinearity is the peak deviation of the output voltage from the best-fit straight line. It is expressed as the ratio of deviation to FSR.
Ripple frequency is at carrier frequency (500 kHz).

7.6 Typical Characteristics

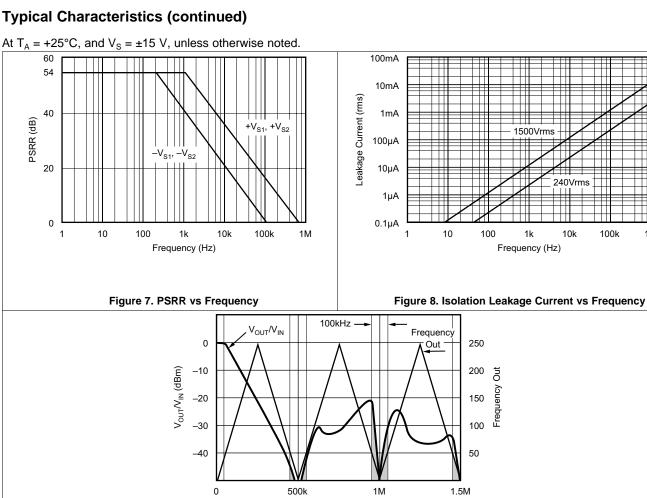
At $T_A = +25^{\circ}C$, and $V_S = \pm 15$ V, unless otherwise noted.





100k

1M



Input Frequency (Hz)

be removed by a low-pass filter at the output.

NOTE: Shaded area shows aliasing frequencies that cannot

Figure 9. Signal Response to Inputs Greater than 250 kHz



8 Detailed Description

8.1 Overview

The ISO124 isolation amplifier uses an input and an output section galvanically isolated by matched 1-pF isolating capacitors built into the plastic package. The input is duty-cycle modulated and transmitted digitally across the barrier. The output section receives the modulated signal, converts it back to an analog voltage and removes the ripple component inherent in the demodulation. Input and output sections are fabricated, then laser trimmed for exceptional circuitry matching common to input and output sections. The sections are then mounted on opposite ends of the package with the isolating capacitors mounted between the two sections. The ISO124 contains 250 transistors.

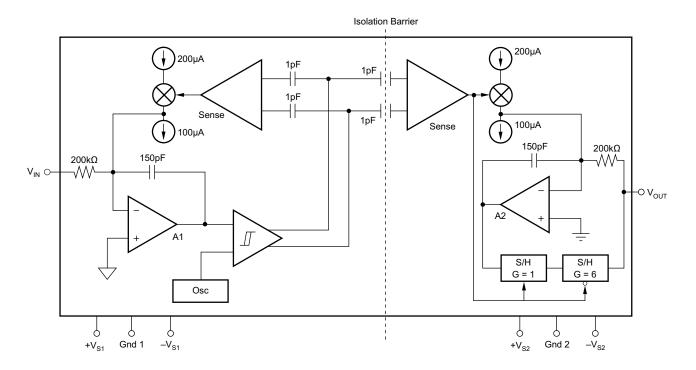
8.1.1 Module

An input amplifier (A1, as shown in *Functional Block Diagram*) integrates the difference between the input current $(V_{IN}/200 \text{ k}\Omega)$ and a switched ±100-µA current source. This current source is implemented by a switchable 200-µA source and a fixed 100-µA current sink. To understand the basic operation of the modulator, assume that $V_{IN} = 0$ V. The integrator will ramp in one direction until the comparator threshold is exceeded. The comparator and sense amp will force the current source to switch; the resultant signal is a triangular waveform with a 50% duty cycle. The internal oscillator forces the current source to switch at 500 kHz. The resultant capacitor drive is a complementary duty-cycle modulation square wave

8.1.2 Demodulator

The sense amplifier detects the signal transitions across the capacitive barrier and drives a switched current source into integrator A2. The output stage balances the duty-cycle modulated current against the feedback current through the 200-k Ω feedback resistor, resulting in an average value at the V_{OUT} pin equal to V_{IN}. The sample-and-hold amplifiers in the output feedback loop serve to remove undesired ripple voltages inherent in the demodulation process.

8.2 Functional Block Diagram





8.3 Feature Description

8.3.1 Isolation Amplifier

The ISO124 is a precision analog isolation amplifier. The input signal is transmitted digitally across a high-voltage differential capacitive barrier. With digital modulation the barrier characteristics do affect signal integrity, resulting in excellent reliability and high-frequency transient immunity.

8.4 Device Functional Modes

The ISO124 does not have any additional functional modes.

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9 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

9.1.1 Carrier Frequency Considerations

The ISO124 amplifier transmits the signal across the isolation barrier by a 500-kHz duty-cycle modulation technique. For input signals having frequencies below 250 kHz, this system works like any linear amplifier. But for frequencies above 250 kHz, the behavior is similar to that of a sampling amplifier. The typical characteristic "Signal Response to Inputs Greater Than 250 kHz" shows this behavior graphically; at input frequencies above 250 kHz. This is the aliasing effect of sampling at frequencies less than two times the signal frequency (the Nyquist frequency). At the carrier frequency and its harmonics, both the frequency and amplitude of the aliasing go to zero.

9.1.2 Isolation Mode Voltage Induced Errors

IMV can induce errors at the output as indicated by the plots of IMV vs Frequency. It should be noted that if the IMV frequency exceeds 250 kHz, the output also will display spurious outputs (aliasing) in a manner similar to that for $V_{IN} > 250$ kHz and the amplifier response will be identical to that shown in the "Signal Response to Inputs Greater Than 250 kHz" typical characteristic. This occurs because IMV-induced errors behave like input-referred error signals. To predict the total error, divide the isolation voltage by the IMR shown in the "IMR versus Frequency" typical performance curve and compute the amplifier response to this input-referred error signal from the data given in the "Signal Response to Inputs Greater Than 250 kHz" typical characteristic. For example, if a 800-kHz 1000-Vrms IMR is present, then a total of [(-60 dB) + (-30 dB)] x (1000 V) = 32-mV error signal at 200 kHz plus a 1-V, 800-kHz error signal will be present at the output.

9.1.3 High IMV dV/dt Errors

As the IMV frequency increases and the dV/dt exceeds 1000 V μ s, the sense amp may start to false trigger, and the output will display spurious errors. The common-mode current being sent across the barrier by the high slew rate is the cause of the false triggering of the sense amplifier. Lowering the power-supply voltages below ±15 V may decrease the dV/dt to 500 V/Ms for typical performance.

9.1.4 High Voltage Testing

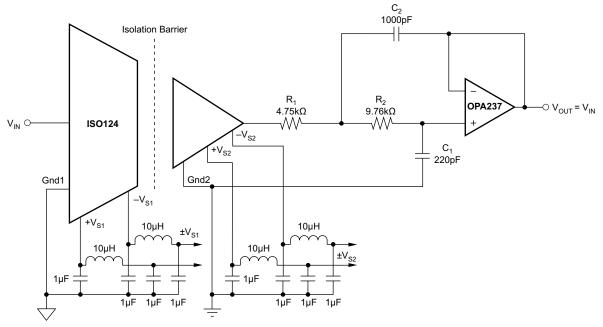
TI has adopted a partial discharge test criterion that conforms to the German VDE0884 Optocoupler Standards. This method requires the measurement of minute current pulses (< 5 pC) while applying 2400-Vrms, 60-Hz high-voltage stress across every ISO124 isolation barrier. No partial discharge may be initiated to pass this test. This criterion confirms transient overvoltage (1.6 × 1500 Vrms) protection without damage to the ISO124. Lifetest results verify the absence of failure under continuous rated voltage and maximum temperature.

This new test method represents the "state-of-the art" for nondestructive high-voltage reliability testing. It is based on the effects of nonuniform fields that exist in heterogeneous dielectric material during barrier degradation. In the case of void nonuniformities, electric field stress begins to ionize the void region before bridging the entire high-voltage barrier. The transient conduction of charge during and after the ionization can be detected externally as a burst of 0.01–0.1-µs current pulses that repeat on each ac voltage cycle. The minimum ac barrier voltage that initiates partial discharge is defined as the "inception voltage." Decreasing the barrier voltage to a lower level is required before partial discharge ceases and is defined as the "extinction voltage." The package insulation processes have been characterized and developed to yield an inception voltage in excess of 2400 Vrms so that transient overvoltage induced partial discharge will cease once the barrier voltage is above 1500 Vrms so that even overvoltage induced partial discharge test methods relied on applying a large enough overvoltage (above rating) to break down marginal parts, but not so high as to damage good ones. Our new partial discharge testing gives us more confidence in barrier reliability than breakdown/no breakdown criteria.



9.2 Typical Applications

9.2.1 Output Filters



For more information concerning output filters refer to Application Notes, SBOA012 and SBFA001.

Figure 10. ISO124 With Output Filter for Improved Ripple

9.2.1.1 Design Requirements

The ISO124 isolation amplifiers (ISO amps) have a small (10 to 20 mVp-p typical) residual demodulator ripple at the output. A simple filter can be added to eliminate the output ripple without decreasing the 50kHz signal bandwidth of the ISO amp.

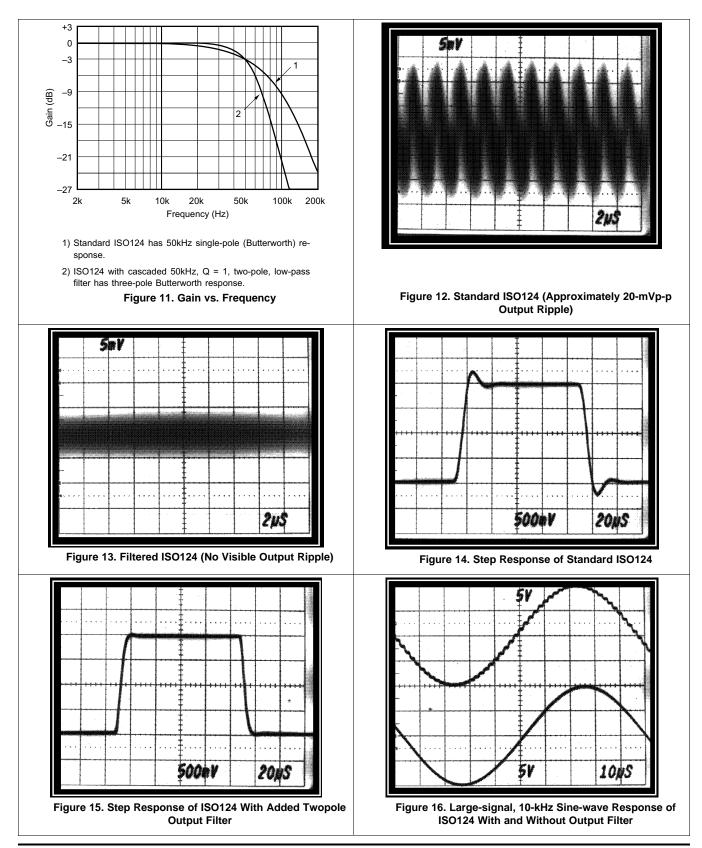
9.2.1.2 Detailed Design Procedure

The ISO124 is designed to have a 50-kHz single-pole (Butterworth) signal response. By cascading the ISO amp with a simple 50-kHz, Q = 1, two-pole, low-pass filter, the overall signal response becomes three-pole Butterworth. The result is a maximally flat 50-kHz magnitude response and the output ripple reduced below the noise level. Figure 10 shows the complete circuit. The two-pole filter is a unity-gain Sallen-Key type consisting of A1, R1, R2, C1, and C2. The values shown give Q = 1 and f–3dB bandwidth = 50 kHz. Because the op amp is connected as a unity-gain follower, gain and gain accuracy of the ISO amp are unaffected. Using a precision op amp such as the OPA602 also preserves the DC accuracy of the ISO amp.



Typical Applications (continued)

9.2.1.3 Application Curves

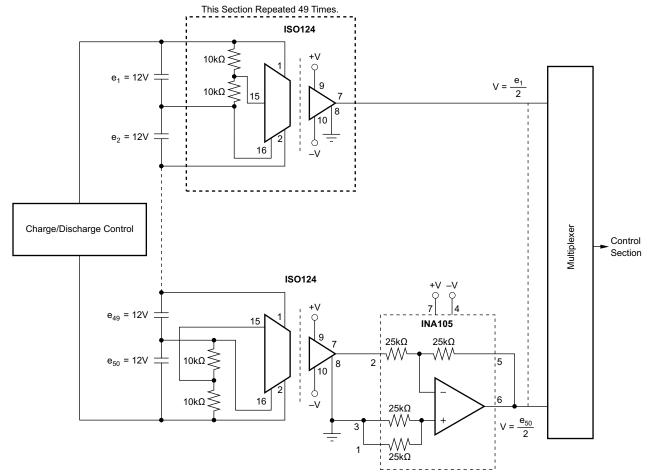




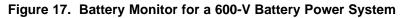
Typical Applications (continued)

9.2.2 Battery Monitor

Figure 17 provides a means to monitor the cell voltage on a 600-V battery stack by using the battery as a power source for the isolated voltage.



(Derives input power from the battery.)



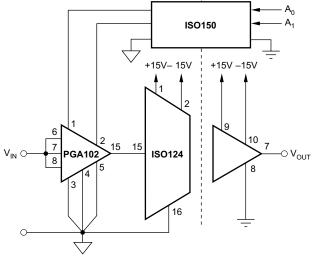
Typical Applications (continued)

9.2.3 Programmable Gain Amplifier

In applications where variable gain configurations are required, a programmable gain amplifier like the PGA102 can be used with the ISO124. Figure 18 uses an ISO150 to provide gain pin selection options to the PGA102.

1







Typical Applications (continued)

9.2.4 Thermocouple Amplifier

For isolated temperature measurements, Figure 19 provides an application solution using the INA114 or INA128 feeding the input stage of the ISO124. The table provides suggested resistor values based on the type of thermistor used in the application.

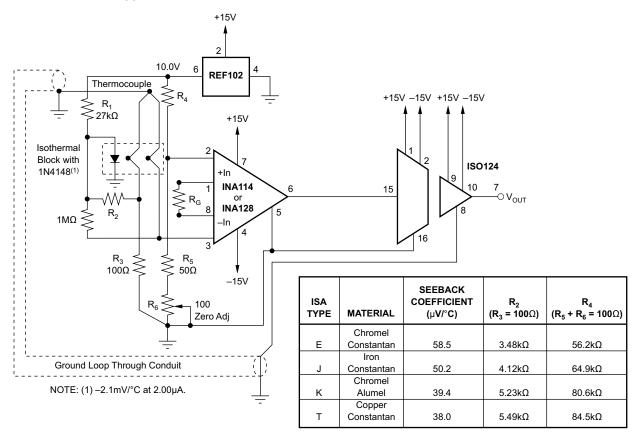


Figure 19. Thermocouple Amplifier With Ground Loop Elimination, Cold Junction Compensation, and Up-scale Burn-out

Typical Applications (continued)

9.2.5 Isolated 4- to 20-mA Instrument Loop

For isolated temperature measurements in a 4- to 20-mA loop, Figure 20 provides a solution using the XTR101 and RCV420. A high-performance PT100 resistance temperature detector (RTD) provides the user with an isolated 0- to 5-V representation of the isolated temperature measurement.

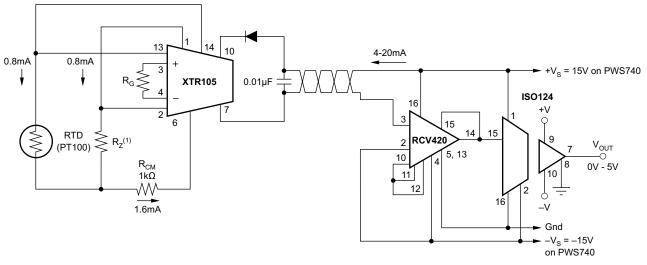
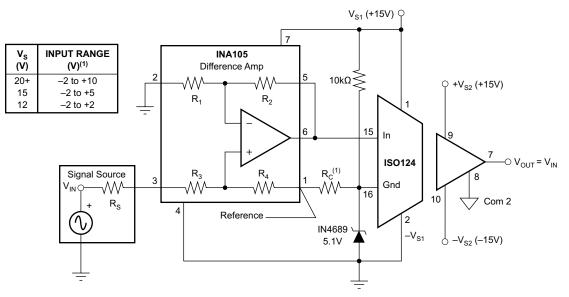


Figure 20. Isolated 4- to 20-mA Instrument Loop (RTD Shown)

9.2.6 Single-Supply Operation of the ISO124 Isolation Amplifier

The circuit shown in Figure 21 uses a 5.1-V Zener diode to generate the negative supply for an ISO12x from a single supply on the high-voltage side of the isolation amplifier. The input measuring range will be dependent on the applied voltage as noted in the accompanying table.



NOTE: Because the amplifier is unity gain, the input range is also the output range. The output can go to -2 V because the output section of the ISO amp operates from dual supplies.

For additional information refer to Application Note SBOA004

Figure 21. Single-Supply Operation of the ISO124 Isolation Amplifier Schematic



Typical Applications (continued)

9.2.7 Input-Side Powered ISO Amplifier

The user side of the ISO124 can be powered from the high voltage side using an isolated DC-DC converter as shown in Figure 22.

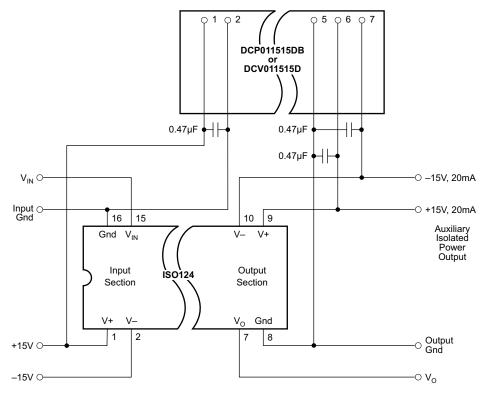


Figure 22. Input-Side Powered ISO Amplifier Schematic

ISO124

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Typical Applications (continued)

9.2.8 Powered ISO Amplifier With Three-Port Isolation

Figure 23 illustrates an application solution that provides isolated power to both the user and high-voltage sides of the ISO124 amplifier.

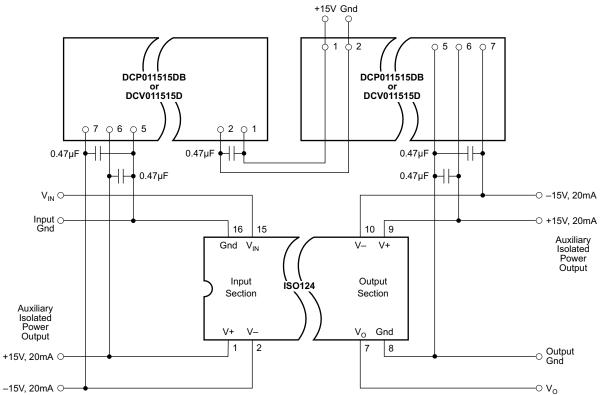


Figure 23. Powered ISO Amplifier With Three-Port Isolation Schematic



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10 Power Supply Recommendations

10.1 Signal and Supply Connections

Each power-supply pin should be bypassed with $1-\mu$ F tantalum capacitors located as close to the amplifier as possible. The internal frequency of the modulator/demodulator is set at 500 kHz by an internal oscillator. Therefore, if it is desired to minimize any feedthrough noise (beat frequencies) from a DC-DC converter, use a π filter on the supplies (see Figure 10). The ISO124 output has a 500-kHz ripple of 20 mV, which can be removed with a simple 2-pole low-pass filter with a 100-kHz cutoff using a low-cost op amp (see Figure 10).

The input to the modulator is a current (set by the 200-k Ω integrator input resistor) that makes it possible to have an input voltage greater than the input supplies, as long as the output supply is at least ±15 V. It is therefore possible, when using an unregulated DC-DC converter, to minimize PSR related output errors with ±5-V voltage regulators on the isolated side and still get the full ±10-V input and output swing.

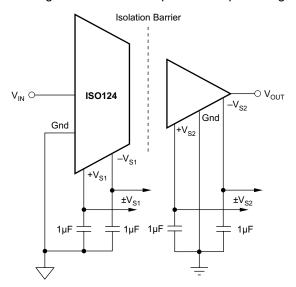


Figure 24. Basic Signal and Power Connections



11 Layout

11.1 Layout Guidelines

To maintain the isolation barrier of the device, the distance between the high-side ground (pin 16 or 28) and the low-side ground (pin 8 or 14) should be kept at maximum; that is, the entire area underneath the device should be kept free of any conducting materials.

11.2 Layout Example

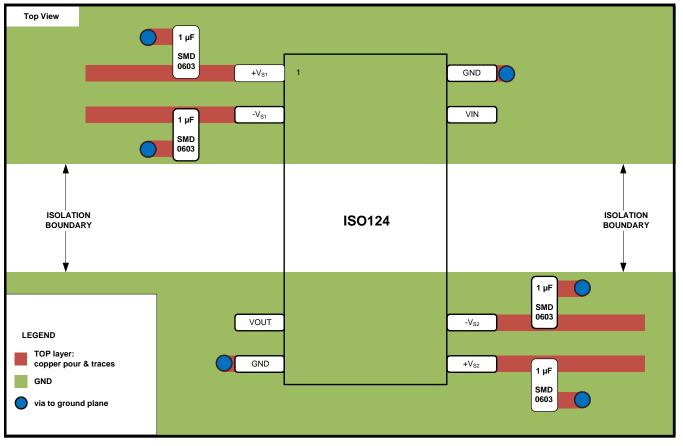


Figure 25. ISO124 Layout Example



12 Device and Documentation Support

12.1 Documentation Support

12.1.1 Related Documentation

- Single-Supply Operation of Isolation Amplifiers, SBOA004
- Simple Output Filter Eliminates ISO Amp Output Ripple and Keeps Full Bandwidth, SBOA012
- FilterPro[™] User's Guide, SBFA001

12.2 Trademarks

FilterPro is a trademark of Texas Instruments. All other trademarks are the property of their respective owners.

12.3 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

12.4 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



10-Sep-2014

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
ISO124P	ACTIVE	PDIP	NVF	8	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-25 to 85	ISO124P	Samples
ISO124U	ACTIVE	SOIC	DVA	8	20	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-25 to 85	ISO 124U	Samples
ISO124U/1K	ACTIVE	SOIC	DVA	8	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-25 to 85	ISO 124U	Samples
ISO124U/1KE4	ACTIVE	SOIC	DVA	8	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-25 to 85	ISO 124U	Samples
ISO124UE4	ACTIVE	SOIC	DVA	8	20	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-25 to 85	ISO 124U	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.



PACKAGE OPTION ADDENDUM

10-Sep-2014

⁽⁶⁾ Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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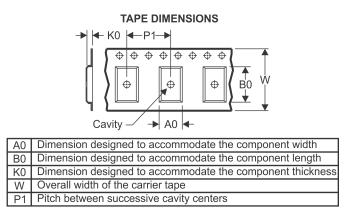
PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	· · ·	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
ISO124U/1K	SOIC	DVA	8	1000	330.0	24.4	10.9	18.3	3.2	12.0	24.0	Q1

TEXAS INSTRUMENTS

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PACKAGE MATERIALS INFORMATION

10-Sep-2014



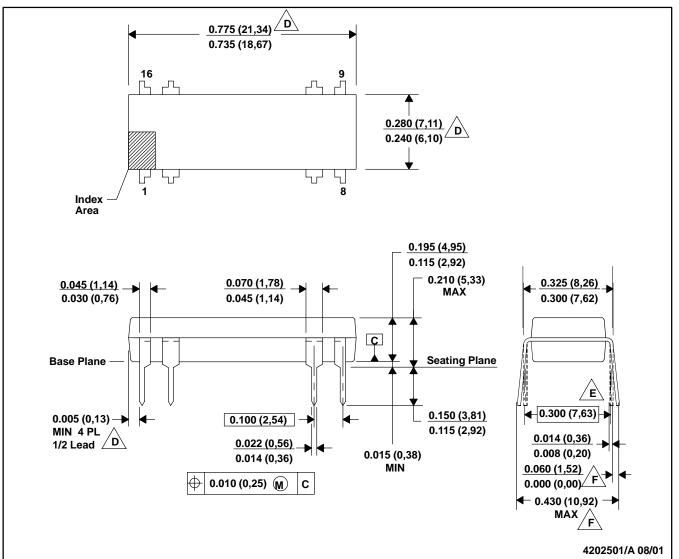
*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
ISO124U/1K	SOIC	DVA	8	1000	367.0	367.0	45.0

MECHANICAL DATA

MPDI072 - AUGUST 2001

PLASTIC DUAL-IN-LINE



A. All linear dimensions are in inches (millimeters).

NVF (R-PDIP-T8/16)

- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-001-BB with the exception of lead count.
- D. Dimensions do not include mold flash or protrusions.
- Mold flash or protrusions shall not exceed 0.010 (0,25). \triangle Dimensions measured with the leads constrained to be perpendicular to Datum C.
- \underline{F} Dimensions are measured at the lead tips with the leads unconstrained.
- G. A visual index feature must be located within the cross-hatched area.

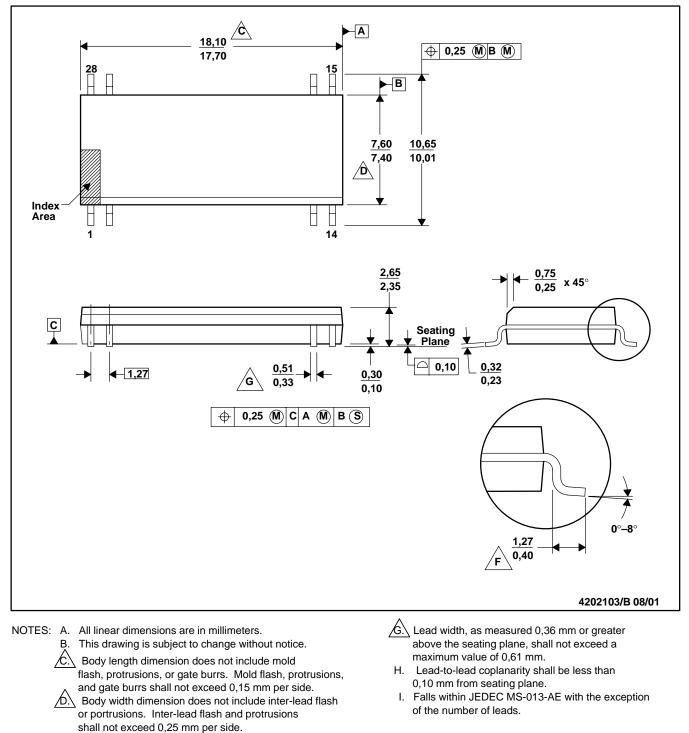


MECHANICAL DATA

MPDS105 - AUGUST 2001

DVA (R-PDSO-G8/28)

PLASTIC SMALL-OUTLINE



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E. The chamfer on the body is optional. If it is not present, a visual index feature must be located within the

Lead dimension is the length of terminal for soldering

cross-hatched area.

to a substrate.

/F.

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